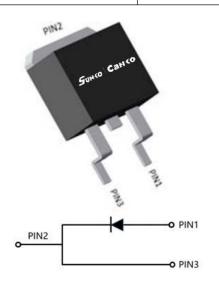


Silicon Carbide Schottky Diode

V_{RRM}	1200V
I _{F (135°C)}	25A
Qc	114nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

• Package: TO-263

• Terminals: Tin plated leads

• Polarity: As marked

■Maximum Ratings (T_c=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D112020BGG2
Reverse voltage (repetitive peak) @ T _j =25°C	V_{RRM}	V	1200
Reverse voltage (Surge Peak) @ T _j =25°C	V _{RSM}	V	1200
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	1200
Continuous forward current @ T _c =25°C T _c =135°C T _c =141°C	IF	Α	56 25 20
Non-repetitive peak forward surge current @ T _c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	160
Power Dissipation@ T _c =25°C T _c =110°C	Ртот	W	214 92
i²t Value@ Tc=25°C ,tp=10ms	∫ i²dt	A ² S	128
Operating junction and Storage temperature range	T _j ,T _{stg}	°C	-55 to +175



■Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	VF	V	I _F =20A, T _j =25°C	1.34	1.55
Forward voltage drop	VF	V	I _F =20A, T _j =175°C	1.86	2.70
Reverse leakage current			V _R =1200V, T _j =25°C	0.5	25
Reverse leakage current	leakage current I _R	μA	V _R =1200V, T _j =175°C	5	-
Total capacitive charge	Qc	nC	V_R =800V, T_j =25°C, QC = $\int_0^{VR}C(V)dV$	114	
			V _R =0V, f=1MHZ	1552	-
Total capacitance	С	pF	V _R =400V, f=1MHZ	107	-
			V _R =800V, f=1MHZ	79	-
Capacitance Stored Energy	Ec	μJ	V _R =800V	29.3	-

■Thermal Characteristics $(T_a=25$ $^{\circ}$ C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	R _{eJ-C}	°C W	0.7

■Characteristics (Typical)

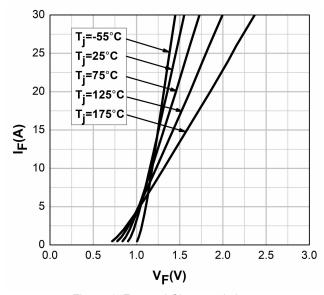


Figure 1. Forward Characteristics

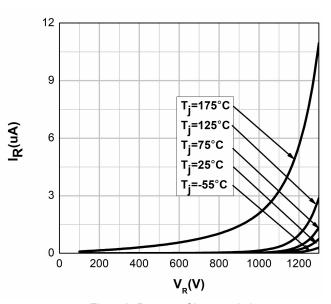
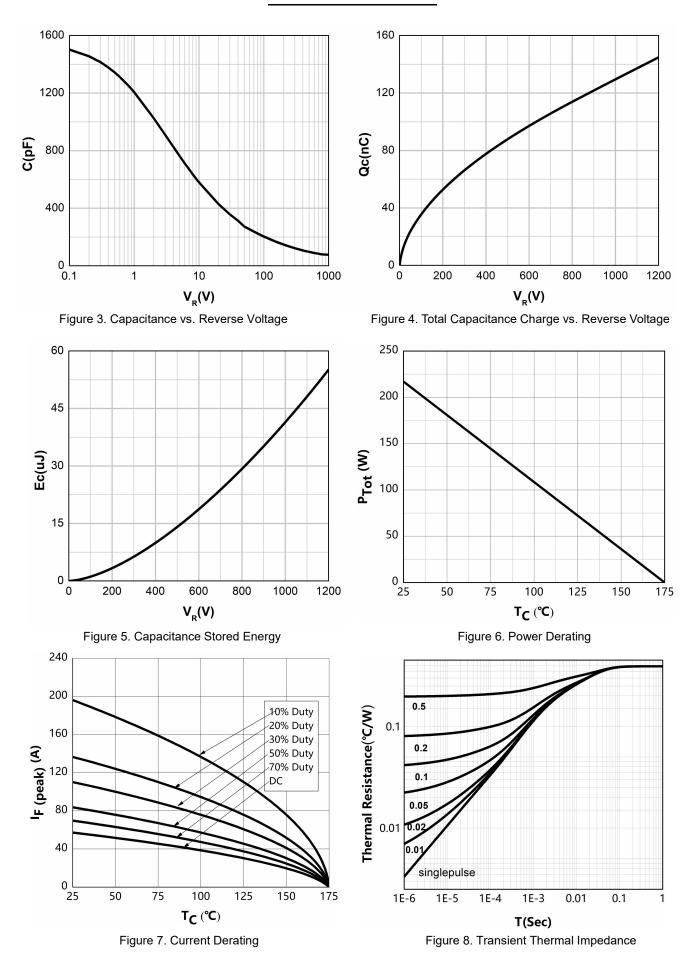


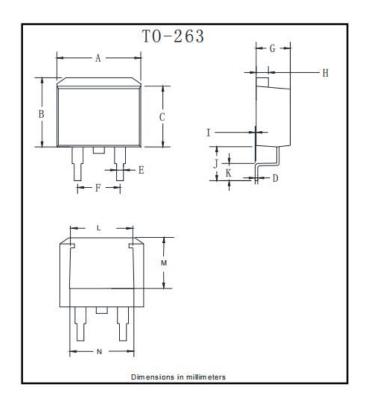
Figure2. Reverse Characteristic







■Outline Dimensions



TO-263			
Dim	Min	Max	
Α	9.5	11.5	
В	9.7	10.5	
С	8.4	9.0	
D	0.28	0.64	
Е	0.68	0.94	
F	4.55	5.6	
G	4.04	5.10	
Н	1.14	1.4	
1	0	0.2	
J	4.9	6.05	
K	1.79	2.79	
L	7.3	7.9	
M	6.2	6.8	
N	7.6	8.2	



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